

Significant Dzyaloshinskii–Moriya interaction at graphene–ferromagnet interfaces due to the Rashba effect

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The possibility of utilizing the rich spin-dependent properties of graphene has attracted much attention in the pursuit of spintronics advances. The promise of high-speed and low-energy-consumption devices motivates the search for layered structures that stabilize chiral spin textures such as topologically protected skyrmions. Here we demonstrate that chiral spin textures are induced at graphene/ferromagnetic metal interfaces. Graphene is a weak spin-orbit coupling material and is generally not expected to induce a sufficient Dzyaloshinskii–Moriya interaction to affect magnetic chirality. We demonstrate that indeed graphene does induce a type of Dzyaloshinskii–Moriya interaction due to the Rashba effect. First-principles calculations and experiments using spin-polarized electron microscopy show that this graphene-induced Dzyaloshinskii–Moriya interaction can have a similar magnitude to that at interfaces with heavy metals. This work paves a path towards two-dimensional-material-based spin-orbitronics.

The unique properties of graphene, including a well-defined single atomic layer thickness, massless linear dispersion of its electronic structure, and long spin diffusion length, have motivated the search for graphene-based phenomena that may enable spintronic applications^{1–3}. Recently, graphene was shown to play key roles in several magnetic phenomena, including a graphene-based tunnel magnetoresistance^{4–6}, enhancement of the spin-injection efficiency^{7,8}, the Rashba effect^{9,10}, the quantum spin Hall effect¹¹ and a large perpendicular magnetic anisotropy (PMA)^{12–14}.

At the same time, recent progress in the field of spin–orbitronics was stimulated by discoveries of phenomena permitting highly efficient electrical control of chiral spin textures—for example, fast domain wall dynamics^{15–18} and skyrmion motion at ultralow current densities^{19–22}. These findings show promise for applications in memory^{23–25} and logic devices²⁶, where the interfacial Dzyaloshinskii–Moriya interaction (DMI)^{27,28} has been recognized as a key ingredient in the creation, stabilization and manipulation of skyrmions^{29–34} and chiral domain walls^{35,36}. Whereas chiral magnetism induced by the interfacial DMI has become an important topic, the DMI at interfaces with graphene was not expected to be significant because, according to the Fert–Levy model³⁷, the DMI scales with spin–orbit coupling (SOC) in the material contacting the ferromagnetic metal layer³⁸ and graphene lacks strong SOC. Recent results reported the observation of enhanced PMA at the graphene/Co interface, even though strong interfacial PMA is also often associated with strong SOC^{14,39}. This suggests that graphene/ferromagnetic metal interfaces are unusual: if graphene enhances

the PMA at interfaces in the absence of strong SOC, then it is interesting to ask if graphene has similarly strong effects on the DMI, helping thereby to promote this and other two-dimensional (2D) materials for spin–orbitronics. In the following, this idea is tested by exploring the interfaces of graphene with cobalt and nickel, where these two ferromagnetic metal elements are chosen for their small lattice mismatch and strong interaction with graphene.

First-principles calculations

The structures of graphene/FM films modelled here are shown in Fig. 1, where a layer of graphene coats the surfaces of three-monolayer (ML) thick hexagonal close-packed (hcp) Co(0001) and face-centred cubic (fcc) Ni(111) films. Arrows schematically indicate clockwise/right-handed and anticlockwise/left-handed (in parentheses) spin spiral chirality. The calculated ground state structure is consistent with previous reports^{4,14}, where one carbon atom of the graphene unit cell is located on top of the adjacent Co(Ni) atom and another carbon atom is located above the hollow site, with a graphene/Co(Ni) distance of about 2.12 (2.15) Å.

We use the chirality-dependent total energy difference approach applied previously for Co/Pt structures^{33,38,40} to calculate the microscopic and micromagnetic DMI constants, d^{tot} and D , respectively, as well as the layer-resolved DMI, d^k , where k indicates individual atomic layers in ferromagnetic metal films. As one can see from Fig. 2 for the calculated results, the largest DMI can reach up to 1.14 meV per atom for a graphene-coated single atomic layer of Co, while for 2 and 3 ML of Co films coated by graphene, the amplitude

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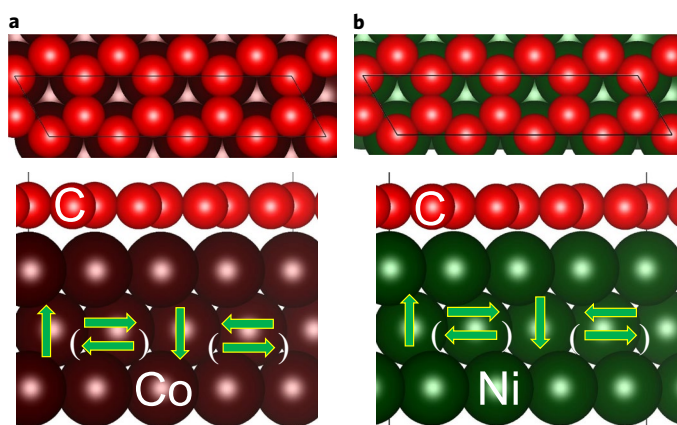


Fig. 1 | Crystal and spin configurations of graphene-coated Co and Ni films used for DMI calculations. **a**, Top- and side-view of graphene on an hcp Co(0001) surface. **b**, Top- and side-view of graphene on an fcc Ni(111) surface. Red, purple and green balls represent carbon, cobalt and nickel atoms, respectively. Clockwise (anticlockwise) spin configurations are schematically shown by arrows.

of d^{tot} drops to 0.16 and 0.49 meV, respectively (Fig. 2a). Moreover, d^{tot} of graphene/Co (brown bars in Fig. 2a) is generally stronger than that of graphene/Ni (green bars in Fig. 2a) for all thicknesses considered. For the micromagnetic DMI, D , we found that its magnitude decreases as a function of the ferromagnetic metal layer thickness for both graphene-coated Co and Ni films (Fig. 2b), due to interfacial origin of the DMI, leading to an inverse proportionality with respect to the ferromagnetic metal layer thickness³⁸.

To elucidate the origin of such a significant DMI in graphene-coated ferromagnetic metals, we then calculated d^k and the associated SOC energy difference, ΔE_{SOC}^k , for the case of graphene-coated 3 ML Co films. Figure 2c shows that the largest layer-resolved DMI, d^k , is located at the interfacial Co layer, labelled as Co1 (blue bar), which is in contact with graphene, while within the layers further from the interface the DMI decays very fast (red and black bars), similar to a previously reported case at the Co/Pt interface³⁸. However, significant differences between graphene/Co and Co/Pt emerge in terms of where the corresponding SOC energy source is located. As shown in Fig. 2d, the largest value of ΔE_{SOC}^k originates from the same Co1 layer rather than from the non-magnetic side of the interface, where it is almost zero. This is drastically different from the Co/Pt case, where the SOC energy difference is mainly contributed by the adjacent Pt layer. These findings indicate that the physical mechanism governing the strength of the DMI in the graphene/Co interface is very different from that in Co/Pt, which is captured by the Fert–Levy model^{37,38}. Instead, in graphene/Co the dominant mechanism is the Rashba-type DMI. According to the latter^{41–43}, the DMI parameter can be roughly expressed as $d = 2k_{\text{R}}A$ at graphene/Co interfaces, where A is the exchange stiffness and $k_{\text{R}} = \frac{2\alpha_{\text{R}}m_e}{\hbar^2}$ is determined by the Rashba coefficient, α_{R} , and effective electron mass, m_e , and \hbar is the reduced Planck constant. The latter in Co was measured⁴⁴ to be about $0.45 m_0$ (with m_0 being the rest mass of the electron), and the exchange stiffness, A , was found to be about 9.5 pJ m^{-1} for graphene/Co(3 ML)/Ru(0001), based on the Curie temperature of this structure (see details in Methods), which is slightly smaller than $A = 15 \text{ pJ m}^{-1}$ in thicker Co films^{34,45}. The Rashba coefficient can then be extracted from $\alpha_{\text{R}} = 2E_0/k_0$, where E_0 is the Rashba splitting at the wave vector k_0 . We calculated the Rashba splitting for a graphene/Co(3 ML) slab by switching on SOC and setting the magnetization along $\langle 11\bar{2}0 \rangle$ and $\langle \bar{1}\bar{1}20 \rangle$. As one can see in Fig. 2e and f, the corresponding band shifts are a

signature of the Rashba effect even though it deviates slightly from the conventional linear dependence given by $\alpha_{\text{R}}(\boldsymbol{\sigma} \times \mathbf{k}) \cdot \mathbf{z}$, where $\boldsymbol{\sigma}$ denotes a vector of the Pauli spin matrices, \mathbf{k} is the wavevector and \mathbf{z} represents a unit vector perpendicular to the interface. The different characters of the band splitting at the $\bar{\Gamma}$ point can be attributed to the fact that Co d orbitals are influenced by different potential gradients due to polarization between graphene and Co that provides an intrinsic electric field and considerably enhances the effective value of SOC at the interface. We chose a band close to the Fermi level at the $\bar{\Gamma}$ point, as shown in Fig. 2f, to estimate the Rashba-type DMI. The Rashba splitting, E_0 , is about 1.28 meV at $k_0 = 0.031 \text{ \AA}^{-1}$, and the Rashba coefficient is thus found to be about 82.6 meV \AA . This leads to $k_{\text{R}} = 9.8 \times 10^{-3} \text{ \AA}^{-1}$ and therefore $d = 0.18 \text{ meV}$ at graphene/Co interface, which is smaller than the value calculated from first-principles ($d = 0.49 \text{ meV}$ for graphene-coated 3 ML Co films). The reason for the smaller DMI value extracted from the Rashba effect can be ascribed to the fact that the Rashba-type DMI was estimated by using only one band close to the Fermi level. As reported in recent studies⁴⁶, the magnitude and sign of α_{R} is generally band-dependent due to band-specific orbital orderings of the orbital angular momentum giving rise to the band-dependent orbital chirality.

Experimental observation of graphene-induced DMI

Experimental tests of the DMI were done using spin-polarized low-energy electron microscopy (SPLEEM), by directly imaging domain walls in perpendicularly magnetized films (see Methods). The films were prepared in situ by molecular beam epitaxy under ultrahigh vacuum (UHV) conditions so that possible extrinsic influences such as growth front roughness are minimal and controlled⁴⁷. The sign of the DMI can be determined by observing the chirality of the domain walls^{32,36,48}, while the strength of the DMI vector, d , can be quantified by measuring the film thickness dependence of a transition from chiral Néel walls (in thin films, where the interfacial DMI influences domain wall texture) to achiral Bloch walls (in thicker films, where dipolar forces outweigh the DMI)^{36,48}. We cannot prepare a free-standing graphene/Co bilayer where the thickness of Co is several ML; instead, high-quality graphene/Co samples were prepared on top of Ru(0001) single-crystal substrates (see Methods).

Figure 3a,b shows compound SPLEEM images highlighting the domain wall spin structure in graphene/Co/Ru(0001) films, where black and grey shades indicate that the magnetization is perpendicular to the film plane with vectors $+M_z$ and $-M_z$, respectively, while colours represent the in-plane magnetization vector according to the colour wheel (inset). For a Co thickness of 3.9 ML (Fig. 3a) the in-plane component of the magnetization within domain walls (white arrows) is perpendicular to the domain wall tangent, and always points from grey domains to black domains (that is, from $-M_z$ and $+M_z$): this indicates that the domain walls have a left-handed/anti-clockwise chiral Néel texture^{36,48}. For a Co thickness of 8.4 ML (Fig. 3b), the magnetization vector within domain walls is aligned parallel to the domain wall tangent: this indicates that the domain wall has a Bloch-type texture. Moreover, the magnetization vector within these domain walls reverses its direction in a number of places, indicating that these domain walls are achiral Bloch walls⁴⁹. This thickness-dependent transition of the domain wall type and chirality can be tracked in more detail using the histogram plotted in Fig. 3c (see Methods). The histogram represents the distribution of the angle α , defined as the angle between the domain wall magnetization vector, \mathbf{m} , and the direction normal to the domain wall, \mathbf{n} (Fig. 3c inset). The distribution of the angle α gradually evolves from a single peak around 0° for a Co thickness of 3.9 ML to double peaks at $\pm 90^\circ$ for a Co thickness of 8.4 ML.

The strength of the DMI in this system can be estimated as $d = 0.11 \pm 0.04 \text{ meV}$ per atom (Fig. 3f), by computing the film-thickness-related dipolar energy difference between Néel- and

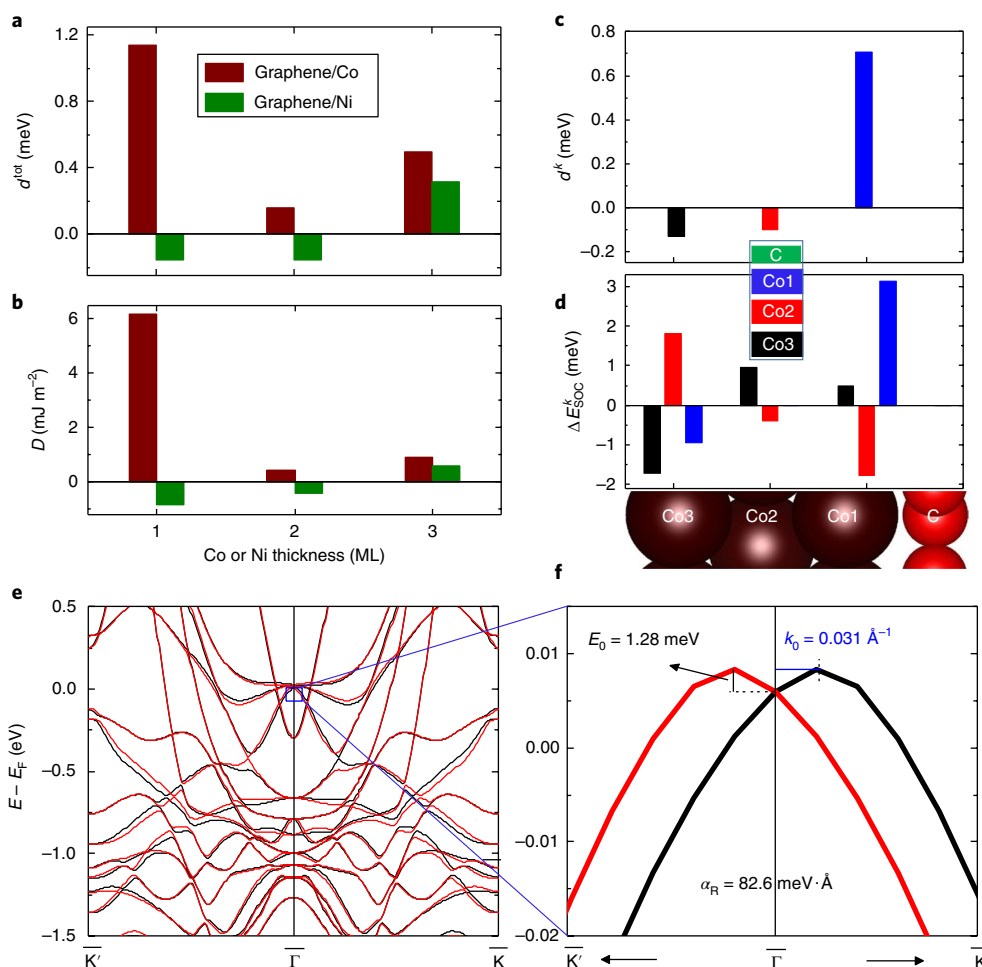


Fig. 2 | Anatomy of DMI for graphene/Co and graphene/Ni bilayers. a, b, Total DMI coefficient d^{tot} (a) and micromagnetic DMI coefficient D (b), as a function of ferromagnetic metal film thickness for graphene/Co (brown bars) and graphene/Ni (green bars) slabs. **c,** Layer-resolved DMI coefficient d^k of the k th layer for a graphene/Co(3 ML) slab. **d,** Atomic-layer-resolved localization of the associated spin-orbit energy ΔE_{SOC}^k . As can be seen, the large DMI coefficient of the Co1 layer (blue bar in c) is associated with large variations of the SO energy $\Delta E_{\text{SOC}}^{\text{Co1}}$ in the Co1 layer (see the corresponding blue bar in d). **e, f,** Band structures for a graphene/Co(3 ML) slab with the magnetization axis along $\langle 1\bar{1}\bar{2}0 \rangle$ (black) and $\langle \bar{1}\bar{1}20 \rangle$ (red) used to estimate the Rashba splitting. The corresponding DMI is found to be about 0.18 meV.

Bloch-textured domain walls. Note that this analysis is independent of the values of exchange interaction and magnetic anisotropy in a given system (see Methods). The DMI parameter contains contributions from both the graphene/Co interface and the Co/Ru interface, and the DMI at Co/Ru needs to be tested so that the DMI at the graphene/Co interface can be deduced. In the Co/Ru(0001) system, a spin reorientation transition from out-of-plane to in-plane occurs from 2 ML Co to 3 ML Co coverage⁵⁰. The step-flow growth mode of this system permits deposition of a Co film of 2.4 ML coverage that consists of alternating strips of 2 ML and 3 ML thickness, featuring out-of-plane- and in-plane domains with well-defined areas (Supplementary Fig. S1). Analogous to ref.⁵¹, the magnetic structure of this sample is an inhomogeneous spin spiral. SPLEEM imaging (Fig. 3d) and analysis of histograms of the domain wall magnetization angle α indicate that the Co/Ru system features right-handed Néel-type chirality. In detail, the split double peak near $\alpha = 180^\circ$ in the histogram plotted in Fig. 3e indicates domain wall spin textures point at roughly 45° with respect to the domain boundary, where the DMI energy is comparable to the dipolar energy difference between Néel- and Bloch-textured domain walls. From this observation, the DMI at Co/Ru can be estimated as $d = -0.05 \pm 0.01$ meV per atom (see Methods). The DMI is highly localized at the interface^{38,40}, and in both Co/Ru and graphene/Co/Ru samples the Co layer is either pseudomorphic

(hcp, for 1 ML Co thickness) or a moiré structure chiefly composed of alternating fcc and hcp regions (for 2 ML or larger Co thickness, see details in Methods). From the experimental DMI values of graphene/Co/Ru and Co/Ru, the DMI of the graphene/Co interface with 4–6 ML Co can be determined to be $d = 0.16 \pm 0.05$ meV per atom (Fig. 3f) (see more details in Methods), which is opposite and about three times as strong as the DMI at the Co/Ru interface. This is consistent with the calculated DMI of $d = 0.18$ meV for graphene/Co[3 ML] based on the Rashba model discussed above.

Towards a giant DMI in graphene-based heterostructures

It was previously proposed that the DMI can be amplified using multilayer structures^{34,36,40,52}. As summarized in Fig. 2, the sign of the DMI for graphene/Ni with a Ni thickness of 1 and 2 ML is negative (clockwise/right-handed chirality), while for graphene/Co the sign is always positive (anticlockwise/left-handed chirality). This suggests the possibility of obtaining large DMI values by building ternary superlattices based on graphene/Co/Ni heterostructures. We tested this hypothesis with first-principles calculations by modelling graphene/[Co/Ni/graphene]_n structures (Fig. 4). The calculated value of d increases with respect to the number of repeating units, n , with a slope less than one. Further calculations indicate that the amplification of the DMI can be further enhanced in

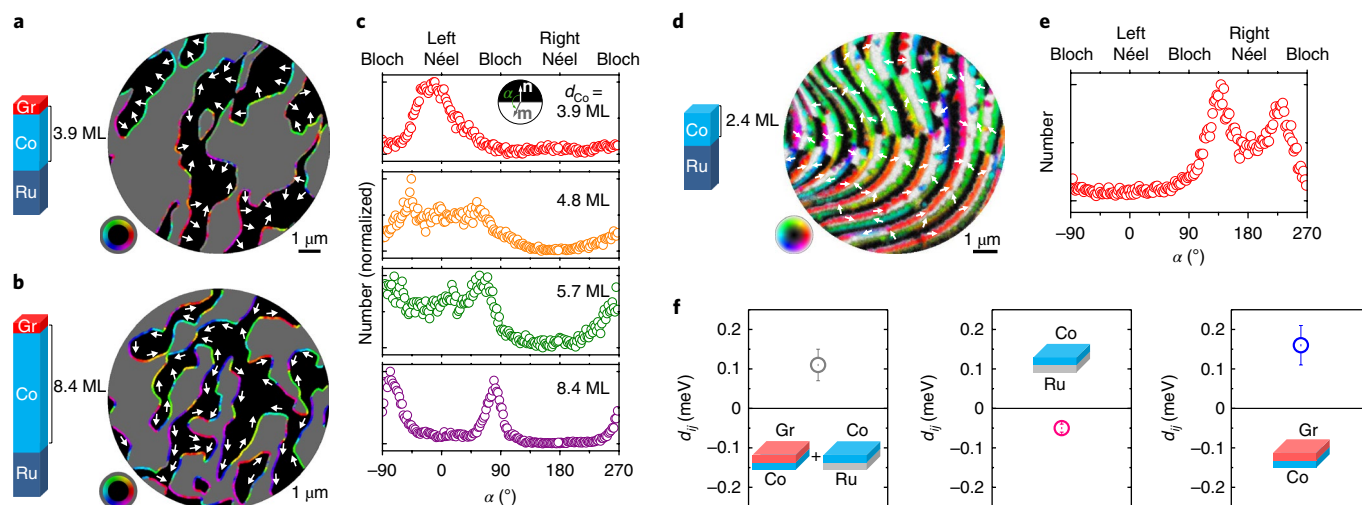


Fig. 3 | Experimental measurement of DMI in graphene/Co by means of SPLEEM. **a, b**, Compound SPLEEM images of graphene/Co/Ru. Scale bar, $1\ \mu\text{m}$. White arrows indicate the orientation of the in-plane magnetization. **c**, Co-thickness-dependent histogram of the angle α counted pixel-by-pixel at the domain wall boundary in graphene/Co/Ru(0001) shows the evolution of the chirality from a left-handed Néel wall (single peak at 0°) to an achiral Bloch wall (double peaks at $\pm 90^\circ$). Inset shows the definition of the angle α , where \mathbf{m} is the in-plane direction of the domain wall magnetization and \mathbf{n} is the in-plane vector normal to the domain boundary, and always points from grey domains to black domains. **d**, Compound SPLEEM image of Co/Ru, where double peaks at 135° and 225° allow the determination of DMI at Co/Ru interface. Scale bar, $1\ \mu\text{m}$. **e**, Histogram of the angle α in Co/Ru indicates right-handed Néel-type rotation. **f**, Experimentally extracted DMI vector strength d_{ij} per atom.

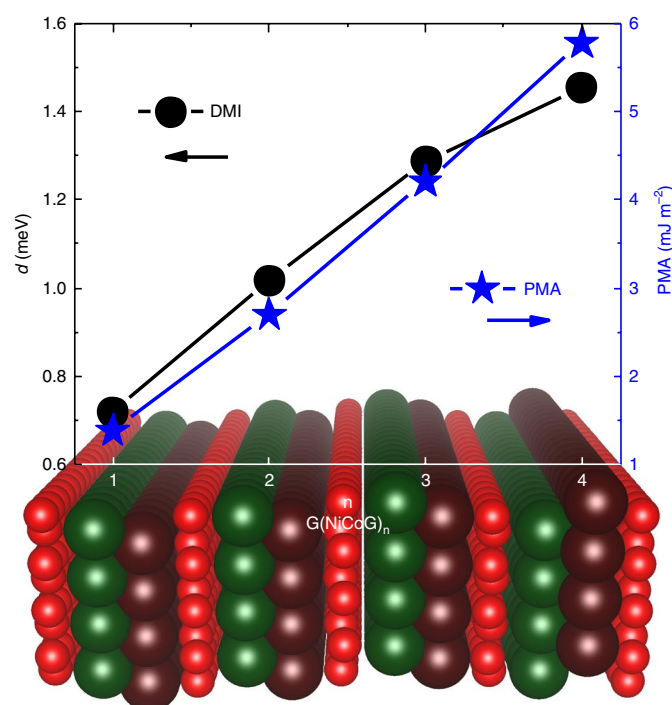


Fig. 4 | DMI and PMA for multilayers of graphene/[Co/Ni/graphene] $_n$ as a function of the junction number n . Black points pointing to the left scale and blue stars pointing to the right scale represent the calculated DMI and PMA values, respectively. Both the DMI and PMA increase approximately linearly as a function of n . The atoms represented by different colours are the same as in Fig. 1.

van der Waals heterostructures where two ferromagnetic metal layers are separated by two MLs of graphene—that is, in multilayers of the graphene/[Co/Ni/bilayer-graphene] $_{(m-1)}$ /Co/Ni/graphene

structure. The result obtained for $m=2$ with $d=1.13\ \text{meV}$ suggests that in multilayers of n repeating units the DMI approaches a value of m times the DMI of a single graphene/Co/Ni/graphene unit. Furthermore, calculating the PMA for graphene/[Co/Ni/graphene] $_n$ heterostructures shows a linear increase with the number of repeating units n that is similar to the behaviour of graphene/[Co/graphene] $_n$ reported before¹⁴.

From the values of the DMI at Co/graphene interfaces obtained in this work, we predict that the graphene-induced DMI should be sufficient to stabilize magnetic chiral spin textures in ultrathin ferromagnetic metal films attached to graphene. For instance, magnetic chiral domain walls and skyrmions have been observed in weak DMI systems ($-0.12\ \text{meV}$ per atom at the Ni/Ir interface⁴⁸, or $0.15\ \text{meV}$ per atom in the Fe/Ni/Cu system³⁶). The proposed [Co/Ni/graphene] $_n$ heterostructure allows simultaneous enhancement of the DMI and PMA, which may be helpful for stabilizing chiral spin textures such as skyrmions with an extremely small size. Moreover, graphene/Co(Ni) grown on copper could be interesting since graphene production on copper is a well-established process⁵³, where the graphene-related interface is expected to dominate the DMI due to the negligible DMI at the Co(Ni)/Cu interface⁵².

In summary, we have discovered both from first-principles calculations and from magnetic imaging experiments that a graphene/ferromagnetic metal interface generates significant DMI. We showed that the physical origin of this DMI is the Rashba effect. The discovery of the DMI induced by graphene, along with its distinctive electronic properties⁵⁴, enhancement of PMA¹⁴, and its ability to act as an excellent capping layer⁵⁵, may open up a new area in the field of spintronics.

Methods

Methods, including statements of data availability and any associated accession codes and references, are available at <https://doi.org/10.1038/s41563-018-0079-4>.

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Author contributions

H.Y. and G.C. conceived the study. H.Y. and S.A.N. performed the ab initio calculations with the help of M.C. H.Y., M.C., S.A.N. and A.F. analysed and interpreted the ab initio results. G.C. and A.A.C.C. carried out the SPLEEM measurements. A.K.S. supervised the SPLEEM facility. G.C., A.A.C.C., A.T.N., K.L. and A.K.S. analysed the SPLEEM results. G.C. derived the DMI strength from experimental data. G.C., A.A.C.C., A.T.N., K.L., A.K.S., E.A.S. and W.A.A.M. interpreted and discussed the experimental result. A.A.C.C., E.A.S. and W.A.A.M. performed XPS measurements. H.Y. and G.C. prepared the manuscript with help from A.A.C.C., A.K.S., S.A.N. and M.C. All authors commented on the manuscript.

Competing interests

The authors declare that they have no competing interests.

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Methods

First-principles calculations. The Vienna ab initio simulation package (VASP) was used in our calculations with electron–core interactions described by the projector augmented wave method, and the exchange correlation energy calculated within the generalized gradient approximation of the Perdew–Burke–Ernzerhof (PBE) form^{36,37}. The cutoff energies for the plane wave basis set used to expand the Kohn–Sham orbitals were chosen to be 520 eV for all calculations. The Monkhorst–Pack scheme was used for the Γ -centred $4 \times 16 \times 1$ k -point mesh. To extract the DMI vectors, the calculations were performed in three steps. First, the corresponding structures were relaxed until the forces become smaller than $0.001 \text{ eV \AA}^{-1}$ to determine the most stable interfacial geometries. In our DMI calculations, we coated 1 to 3 ML of hcp Co(0001) or fcc Ni(001) films with graphene in a 4×1 surface unit cell with $\pi/2$ spin rotations (Fig. 1), we also calculated hcp- or fcc-stacked Co films on bare Ru(0001) in the same unit cell. Next, the Kohn–Sham equations were solved with no spin–orbit interaction taken into account to determine the charge distribution of the system's ground state. Finally, spin–orbit coupling was included and the self-consistent total energy of the systems was determined as a function of the constrained magnetic moments. We employ the same method as used for DMI calculations in frustrated bulk systems and insulating chiral-lattice magnets⁵⁸ and adapted to the case of interfaces. As for the Rashba effect, we adopted the same approach as in an earlier study⁵⁹ (see also Supplementary Fig. S2 and corresponding discussion).

Sample preparation. We conducted the experiments in the SPLEEM system at the National Center for Electron Microscopy of Lawrence Berkeley National Laboratory. All samples were prepared under UHV conditions, with a base pressure better than 4.0×10^{-11} torr. Ru(0001) substrates were cleaned by repeated flash annealing at 1,470 K in a 3.0×10^{-8} torr O_2 atmosphere with final annealing at 1,430 K under UHV. After such procedure, we did not observe any trace of contaminants by Auger electron spectroscopy (AES) and LEEM. Furthermore, high-quality low-energy electron diffraction (LEED) patterns were obtained, indicating a well-ordered surface.

Graphene was grown by the chemical vapour deposition method⁶⁵, where we kept the substrate at 920 K under an ethylene atmosphere (10^{-8} torr) for around 15 minutes, while observing the process by LEEM. Preparing graphene at low growth temperature is required for a good intercalation process, since defects within the graphene layer assist the cobalt migration. The presence of graphene was confirmed by the moiré pattern in LEED⁶⁰ (see Supplementary Fig. S3). After cooling graphene/Ru(0001) to room temperature, 1 ML Co was deposited by electron beam evaporation at rates of 0.18 ML per minute, and intercalated by annealing at 620 K for three minutes⁶¹. To achieve higher Co thicknesses, we repeated the intercalation of additional 1 ML doses of Co, exploring layer thicknesses up to 24 ML Co. The Co growth rate was calibrated by monitoring the LEEM image intensity during the deposition of Co directly onto bare Ru (0001). For the Co/Ru films, Co layers were deposited on Ru(0001) by electron beam evaporation at a substrate temperature of 460 K, promoting the step flow growth mode. The atomic layer thickness of the Co deposited is known directly from monitoring the step flow growth in situ in LEEM.

The growth of magnetic layers was monitored by LEED. All the samples show sharp diffraction patterns, indicating well-defined crystallinity and epitaxy (see Supplementary Fig. S4). The first Co layer grows pseudomorphically on clean Ru, consistent with ref. 62. In the presence of graphene, the pseudomorphic structure of 1 ML Co between graphene and Ru(0001) has been reported by scanning tunnelling microscopy in refs 61,63, where the structure of the graphene moiré pattern remains identical before and after the intercalation of the first monolayer Co, proving that the Co monolayer under the graphene is pseudomorphic with the Ru(0001). For thicker Co coverages, superstructures near the first-order LEED spots (see example in Supplementary Fig. S4e) have been attributed to relaxation of the lattice mismatch between Co and Ru, resulting in an epitaxial relationship that features Co layers with essentially bulk structure, where lattice mismatch strain is relieved at the Co/Ru interface in a moiré structure composed of alternating hcp- and fcc-stacked regions⁶².

In the graphene/Co/Ru(0001) system, increasing the Co film thickness weakens the PMA, analogous to the findings reported in ref. 12. This allows us to tailor the effective magnetic anisotropy of our samples by approaching the spin reorientation transition point from out-of-plane to in-plane, where the effective anisotropy can become extremely small. Proximity to the spin reorientation transition results in a rather large width of the domain walls⁶⁴, which is useful for the precise mapping of domain wall spin textures in the SPLEEM.

Possible signs of Co diffusion into Ru were monitored by X-ray photoelectron spectroscopy (XPS) in Co/Ru (0001) films grown by the same procedure as described above. We conducted the XPS experiment at Centro de Desenvolvimento da Tecnologia Nuclear. The measurements were carried out in a UHV chamber (base pressure better than 2.0×10^{-10} mbar) using an Al $K\alpha$ x-ray source with the output power set at 300 W and a VG Microtech hemispherical electron energy analyser CLAM 2/1 VU. Normal emission scans with a pass energy of 50 eV were acquired. Following the Co and Ru XPS signal before and after the annealing procedure, we observed no evidence of Co–Ru interdiffusion (see Supplementary Fig. S5).

Real-space imaging. In the SPLEEM system, real-space images were acquired using three orthogonal electron beam spin-alignments such that magnetic contrast along three orthogonal directions corresponds to the out-of-plane magnetization direction and two orthogonal in-plane axes⁶⁵, as shown in Supplementary Fig. S1a–c. SPLEEM images map the magnetization of the sample in the sense that the intensity in each pixel represents the dot product of the spin polarization vector \mathbf{P} of the illumination beam and the magnetization vector \mathbf{M} . The lateral spatial resolution of the SPLEEM at the Berkeley lab is $\sim 15 \text{ nm}$, while the measured domain wall width in the systems studied here is between 150 nm and 350 nm. The energy of the incident electron beam was set to 3.6 eV for graphene/Co/Ru and 5 eV for Co/Ru; these values were chosen to optimize the magnetic contrast. All images were obtained with samples at room temperature. The images are represented in a grey scale, where a black and a white contrast correspond to the magnetization vector pointing into the film plane ($+M_z$) and out of the plane ($-M_z$), respectively, as shown in Supplementary Fig. S1a–c. To highlight domain wall spin structures, the triplets of SPLEEM images representing out-of-plane and orthogonal in-plane magnetization components are combined into single compound images, as shown in Supplementary Fig. S1e. In this projection, colours represent the in-plane magnetization as indicated by the colour wheel (inset), and black and grey values represent the perpendicular magnetization component, $+M_z$ and $-M_z$, respectively.

Analysis of chirality. The method to analyse domain wall chirality from the SPLEEM images is the same as described previously⁴⁸. First, along all domain walls the domain wall normal direction (\mathbf{n}) is determined from the out-of-plane magnetization SPLEEM images, where \mathbf{n} is defined as a vector pointing from spin-down ($-M_z$) to spin-up ($+M_z$) domains. Then, at all pixels along the domain wall centrelines, the in-plane magnetization direction (\mathbf{m}) is measured from the grey values of the two in-plane SPLEEM images. To improve the signal-to-noise ratio, in this step each pixel is averaged with its three by three nearest-neighbour pixels. Finally, we compute the angle α , defined as the angle between \mathbf{m} and \mathbf{n} (inset of Fig. 3c), and we calculate its distribution along all domain wall centrelines, as represented by the histograms.

Estimating the exchange stiffness. The strength of the Rashba-induced DMI at graphene/Co interfaces depends on the value of the exchange stiffness, which, in very thin films, can be lower than the Co bulk value of 15 pJ m^{-1} (ref. 34). The exchange stiffness in graphene/Co/Ru(0001) samples can be estimated from the Curie temperature, which is obtained by real-time SPLEEM measurement of the temperature-dependent magnetization. The Curie temperature T_C depends on the exchange stiffness A as $T_C = \frac{2z_{\text{NN}}(g_j - 1)^2 J_{\text{ex}}}{3k_B} (J + 1)$, where $A = 2 \frac{J_{\text{ex}} S^2 z_{\text{NC}}}{a}$ (ref. 66), z_{NN} is the number of nearest-neighbour atoms, g_j is the g -factor, k_B is the Boltzmann constant, J is the total angular momentum quantum number, S is the spin quantum number, z_{NC} is the number of atoms in a unit cell, and a is the lattice constant. For graphene/Co(3 ML)/Ru(0001) we find that the Curie temperature is about 861 K (see Supplementary Fig. S6). In this sample structure $z_{\text{NN}} = 12$, $g_j = 2.09$, $k_B = 1.38 \times 10^{-23} \text{ m}^2 \text{ kg s}^{-2} \text{ K}^{-1}$, $J = 1/2$, $S = 1/2$, $z_{\text{NC}} = 4$, so the result $T_C^{\text{3ML Co}} = 861 \text{ K}$ leads to the experimental estimate of A as 9.5 pJ m^{-1} for 3 ML Co. Measuring thicker films we find that for graphene/Co(4 ML)/Ru the magnetic contrast remains strong up to about 943 K, but in this temperature range the films are not stable. Thus a lower limit of A in graphene/Co(4 ML)/Ru can be estimated as 10.4 pJ m^{-1} and an upper limit of the exchange stiffness in films of any thickness is the value of bulk Co (15 pJ m^{-1}).

Estimating the DMI strength. The orientation of magnetization within the domain wall with respect to the domain boundary direction in Fig. 3 allows one to estimate the strength of the interfacial DMI, using methods described in more detail in refs 36,48. Briefly, the free energies of Néel and Bloch walls can be written as $E^{\text{Néel}} = E_{\text{ex}}^{\text{Néel}} + E_{\text{d}}^{\text{Néel}} + E_{\text{DM}}^{\text{Néel}} + E_{\text{DM}}^{\text{Néel}}$ and $E^{\text{Bloch}} = E_{\text{ex}}^{\text{Bloch}} + E_{\text{d}}^{\text{Bloch}} + E_{\text{DM}}^{\text{Bloch}} + E_{\text{DM}}^{\text{Bloch}}$, respectively, where E_{ex} , E_{d} , E_{DM} and E_{DM} correspond to exchange energy, magnetic anisotropy energy, dipolar energy and DMI energy of the walls, respectively. Néel walls are favoured when $E^{\text{Néel}} < E^{\text{Bloch}}$; and since both the exchange and magnetic anisotropy energy are degenerate for Néel- and Bloch-type walls and the interfacial DMI energy vanishes for Bloch-type walls⁴⁹, this inequality can be expressed as $E_{\text{d}}^{\text{Néel}} + E_{\text{DM}}^{\text{Néel}} < E_{\text{d}}^{\text{Bloch}}$. Likewise, Bloch walls are favoured when $E_{\text{d}}^{\text{Néel}} + E_{\text{DM}}^{\text{Néel}} > E_{\text{d}}^{\text{Bloch}}$. Thus, from observations of thickness-dependent transitions from Néel to Bloch walls, the range of $E_{\text{DM}}^{\text{Néel}}$ can be bracketed by computing the dipolar energy contributions. Samples with thicknesses below the wall-type transition feature Bloch walls and $E_{\text{d}}^{\text{Bloch}} - E_{\text{d}}^{\text{Néel}} < E_{\text{DM}}^{\text{Néel}}$, whereas in samples with thicknesses above the transition walls have the Néel structure and $E_{\text{DM}}^{\text{Néel}} < E_{\text{d}}^{\text{Bloch}} - E_{\text{d}}^{\text{Néel}}$. Using the method for calculating the dipolar energy difference as described in refs 36,48, the dipolar energy constant $D_{\text{dip}} = \frac{\mu_0 (d_{\text{Co}} \mu_{\text{Co}})^2}{8\pi a_{\text{eff}}^3}$ (ref. 48), where $\mu_0 = 4\pi \times 10^{-7} \text{ H m}^{-1}$, $\mu_{\text{B}} = 9.27 \times 10^{-24} \text{ A m}^2$, $\mu_{\text{Co}} = 1.7\mu_{\text{B}}$, $a_{\text{eff}} = 2.51 \text{ \AA}$. Using the Matlab software, we numerically calculate the dipolar energy difference $E_{\text{d}}^{\text{Bloch}} - E_{\text{d}}^{\text{Néel}}$ of graphene/Co/Ru(0001) with various thicknesses. In graphene/Co/Ru(0001) films, observations of Néel walls for Co $\sim 3.9 \text{ ML}$, tilted

walls for Co = 4.8 ML, and Bloch-like walls for Co = 5.7 ML lead to values of $E_d^{\text{Bloch}} - E_d^{\text{Néel}} = -0.38$ meV per atom, -0.58 meV per atom and -0.81 meV per atom, respectively. Note that the dipolar energy cost of Néel walls $E_d^{\text{Néel}}$ is greater than that of Bloch walls E_d^{Bloch} (refs. 36,48); therefore, all numbers calculated above are negative. In the calculation, the width of domain walls is chosen as 150 nm, which is consistent with estimates of both Néel and Bloch walls observed in the SPLEEM images. For a hexagonal lattice, $E_{\text{DM}}^{\text{Néel}} = -\sqrt{3}\pi d$ (ref. 48), where d is the magnitude of the DMI vector. Therefore d in the graphene/Co/Ru(0001) system can be estimated as $d = 0.11 \pm 0.04$ meV per atom. Similarly, d in the Co/Ru system can be estimated as $d = -0.05 \pm 0.01$ meV per atom based on the 3 ML Co/Ru result (Fig. 3e), where a roughly 45° tilted magnetization with respect to the domain boundary (see two peaks at 135° and 225° in Fig. 3e) indicates that the dipolar energy difference between Néel and Bloch domain walls $E_d^{\text{Bloch}} - E_d^{\text{Néel}}$ is comparable to the DMI energy $E_{\text{DM}}^{\text{Néel}}$. Here the error bar is given by the uncertainty of the magnetization profile within the in-plane region³⁶. Therefore, d at the graphene/Co interface with Co thicknesses in the range 4–6 ML can be estimated as 0.16 ± 0.05 meV per atom, based on the estimated d values in graphene/Co/Ru(0001) and in Co/Ru(0001).

Data availability. The data that support the findings of this study are available from the corresponding authors upon reasonable request.

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